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# 4-Mbit (512K words × 8-bit) Static RAM

## Features

- High speed
  - $t_{AA} = 10$  ns
- Low active and standby currents
  - Active current:  $I_{CC} = 38$  mA typical
  - Standby current:  $I_{SB2} = 6$  mA typical
- Operating voltage range: 1.65 V to 2.2 V, 2.2 V to 3.6 V, and 4.5 V to 5.5 V
- 1.0 V data retention
- TTL-compatible inputs and outputs
- Pb-free 36-pin SOJ and 44-pin TSOP II packages

## Functional Description

CY7C1049GN is a high-performance CMOS fast static RAM device organized as 512K words by 8-bits.

Data writes are performed by asserting the Chip Enable ( $\overline{CE}$ ) and Write Enable ( $\overline{WE}$ ) inputs LOW, while providing the data on I/O<sub>0</sub> through I/O<sub>7</sub> and address on A<sub>0</sub> through A<sub>18</sub> pins.

Data reads are performed by asserting the Chip Enable ( $\overline{CE}$ ) and Output Enable ( $\overline{OE}$ ) inputs LOW and providing the required address on the address lines. Read data is accessible on the I/O lines (I/O<sub>0</sub> through I/O<sub>7</sub>).

All I/Os (I/O<sub>0</sub> through I/O<sub>7</sub>) are placed in a high-impedance state during the following events:

- The device is deselected ( $\overline{CE}$  HIGH)
- The control signal  $\overline{OE}$  is de-asserted

The logic block diagram is on page 2.

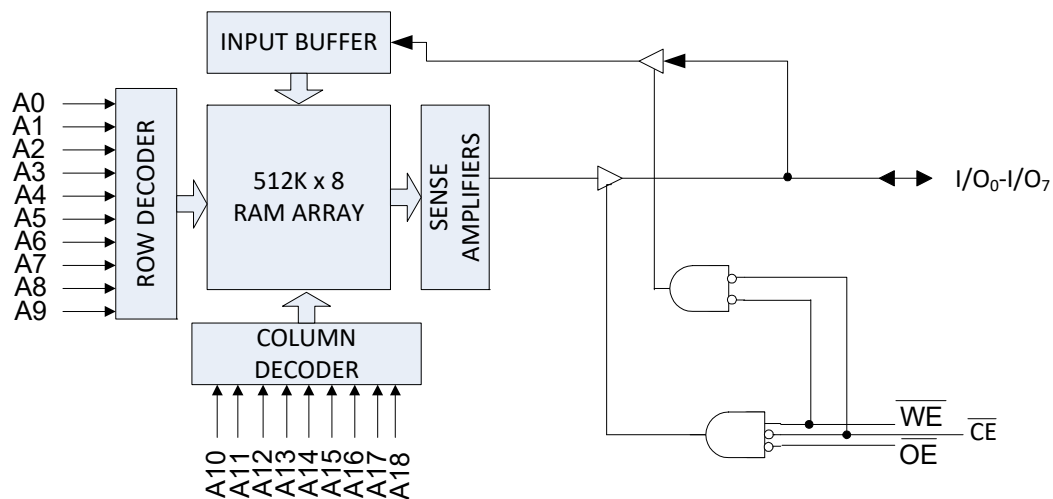
## Product Portfolio

| Product      | Range      | V <sub>CC</sub> Range (V) | Speed<br>(ns)<br><br>10/15 | Power Dissipation              |     |                                |     |
|--------------|------------|---------------------------|----------------------------|--------------------------------|-----|--------------------------------|-----|
|              |            |                           |                            | Operating I <sub>CC</sub> (mA) |     | Standby, I <sub>SB2</sub> (mA) |     |
|              |            |                           |                            | f = f <sub>max</sub>           |     |                                |     |
|              |            |                           |                            | Typ <sup>[1]</sup>             | Max | Typ <sup>[1]</sup>             | Max |
| CY7C1049GN18 | Industrial | 1.65 V–2.2 V              | 15                         | –                              | 40  | 6                              | 8   |
| CY7C1049GN30 |            | 2.2 V–3.6 V               | 10                         | 38                             | 45  |                                |     |
| CY7C1049GN   |            | 4.5 V–5.5 V               | 10                         | 38                             | 45  |                                |     |

### Note

1. Typical values are included only for reference and are not guaranteed or tested. Typical values are measured at V<sub>CC</sub> = 1.8 V (for a V<sub>CC</sub> range of 1.65 V–2.2 V), V<sub>CC</sub> = 3 V (for a V<sub>CC</sub> range of 2.2 V–3.6 V), and V<sub>CC</sub> = 5 V (for a V<sub>CC</sub> range of 4.5 V–5.5 V), T<sub>A</sub> = 25 °C.

## Logic Block Diagram – CY7C1049GN

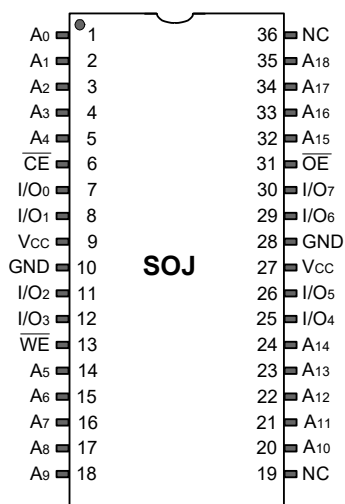


## Contents

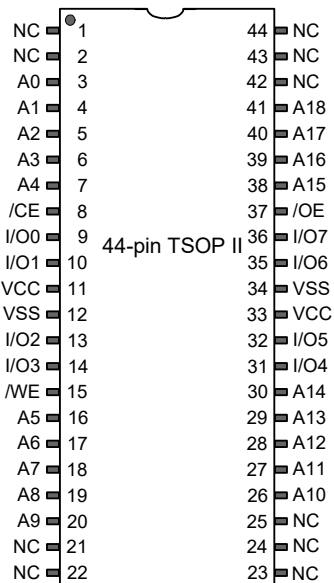
|                                             |           |                                                      |           |
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## Pin Configurations

**Figure 1. 36-pin SOJ pinout** <sup>[2]</sup>



**Figure 2. 44-pin TSOP II pinout, Single Chip Enable** <sup>[2]</sup>



**Note**

- NC pins are not connected internally to the die.

## Maximum Ratings

Exceeding maximum ratings may impair the useful life of the device. These user guidelines are not tested.

Storage temperature ..... -65 °C to +150 °C

Ambient temperature  
with power applied ..... -55 °C to +125 °C

Supply voltage  
on  $V_{CC}$  relative to GND <sup>[3]</sup> ..... -0.5 to  $V_{CC} + 0.5$  V

DC voltage applied to outputs  
in HI-Z State <sup>[3]</sup> ..... -0.5 V to  $V_{CC} + 0.5$  V

DC input voltage <sup>[3]</sup> ..... -0.5 V to  $V_{CC} + 0.5$  V

Current into outputs (in LOW state) ..... 20 mA

Static discharge voltage  
(MIL-STD-883, Method 3015) ..... > 2001 V

Latch-up current ..... > 140 mA

## Operating Range

| Grade      | Ambient Temperature | $V_{CC}$                                              |
|------------|---------------------|-------------------------------------------------------|
| Industrial | -40 °C to +85 °C    | 1.65 V to 2.2 V,<br>2.2 V to 3.6 V,<br>4.5 V to 5.5 V |

## DC Electrical Characteristics

Over the operating range of -40 °C to 85 °C

| Parameter | Description                                   | Test Conditions                                                                                                                            | 10 ns/15 ns          |                    |                      | Unit |
|-----------|-----------------------------------------------|--------------------------------------------------------------------------------------------------------------------------------------------|----------------------|--------------------|----------------------|------|
|           |                                               |                                                                                                                                            | Min                  | Typ <sup>[4]</sup> | Max                  |      |
| $V_{OH}$  | Output HIGH voltage                           | 1.65 V to 2.2 V $V_{CC} = \text{Min}, I_{OH} = -0.1 \text{ mA}$                                                                            | 1.4                  | —                  | —                    | V    |
|           |                                               | 2.2 V to 2.7 V $V_{CC} = \text{Min}, I_{OH} = -1.0 \text{ mA}$                                                                             | 2                    | —                  | —                    |      |
|           |                                               | 2.7 V to 3.0 V $V_{CC} = \text{Min}, I_{OH} = -4.0 \text{ mA}$                                                                             | 2.2                  | —                  | —                    |      |
|           |                                               | 3.0 V to 3.6 V $V_{CC} = \text{Min}, I_{OH} = -4.0 \text{ mA}$                                                                             | 2.4                  | —                  | —                    |      |
|           |                                               | 4.5 V to 5.5 V $V_{CC} = \text{Min}, I_{OH} = -4.0 \text{ mA}$                                                                             | 2.4                  | —                  | —                    |      |
|           |                                               | 4.5 V to 5.5 V $V_{CC} = \text{Min}, I_{OH} = -0.1 \text{ mA}$                                                                             | $V_{CC} - 0.5^{[5]}$ | —                  | —                    |      |
| $V_{OL}$  | Output LOW voltage                            | 1.65 V to 2.2 V $V_{CC} = \text{Min}, I_{OL} = 0.1 \text{ mA}$                                                                             | —                    | —                  | 0.2                  | V    |
|           |                                               | 2.2 V to 2.7 V $V_{CC} = \text{Min}, I_{OL} = 2 \text{ mA}$                                                                                | —                    | —                  | 0.4                  |      |
|           |                                               | 2.7 V to 3.6 V $V_{CC} = \text{Min}, I_{OL} = 8 \text{ mA}$                                                                                | —                    | —                  | 0.4                  |      |
|           |                                               | 4.5 V to 5.5 V $V_{CC} = \text{Min}, I_{OL} = 8 \text{ mA}$                                                                                | —                    | —                  | 0.4                  |      |
| $V_{IH}$  | Input HIGH voltage                            | 1.65 V to 2.2 V —                                                                                                                          | 1.4                  | —                  | $V_{CC} + 0.2^{[3]}$ | V    |
|           |                                               | 2.2 V to 2.7 V —                                                                                                                           | 2                    | —                  | $V_{CC} + 0.3^{[3]}$ |      |
|           |                                               | 2.7 V to 3.6 V —                                                                                                                           | 2                    | —                  | $V_{CC} + 0.3^{[3]}$ |      |
|           |                                               | 4.5 V to 5.5 V —                                                                                                                           | 2                    | —                  | $V_{CC} + 0.5^{[3]}$ |      |
| $V_{IL}$  | Input LOW voltage                             | 1.65 V to 2.2 V —                                                                                                                          | -0.2 <sup>[3]</sup>  | —                  | 0.4                  | V    |
|           |                                               | 2.2 V to 2.7 V —                                                                                                                           | -0.3 <sup>[3]</sup>  | —                  | 0.6                  |      |
|           |                                               | 2.7 V to 3.6 V —                                                                                                                           | -0.3 <sup>[3]</sup>  | —                  | 0.8                  |      |
|           |                                               | 4.5 V to 5.5 V —                                                                                                                           | -0.5 <sup>[3]</sup>  | —                  | 0.8                  |      |
| $I_{IX}$  | Input leakage current                         | $GND \leq V_{IN} \leq V_{CC}$                                                                                                              | -1                   | —                  | +1                   | μA   |
| $I_{OZ}$  | Output leakage current                        | $GND \leq V_{OUT} \leq V_{CC}$ , Output disabled                                                                                           | -1                   | —                  | +1                   | μA   |
| $I_{CC}$  | Operating supply current                      | Max $V_{CC}$ , $I_{OUT} = 0 \text{ mA}$ , CMOS levels                                                                                      | —                    | 38                 | 45                   | mA   |
|           |                                               | $f = 100 \text{ MHz}$                                                                                                                      | —                    | —                  | 40                   |      |
| $I_{SB1}$ | Automatic CE power-down current – TTL inputs  | Max $V_{CC}$ , $\overline{CE} \geq V_{IH}$ , $V_{IN} \geq V_{IH}$ or $V_{IN} \leq V_{IL}$ , $f = f_{MAX}$                                  | —                    | —                  | 15                   | mA   |
| $I_{SB2}$ | Automatic CE power-down current – CMOS inputs | Max $V_{CC}$ , $\overline{CE} \geq V_{CC} - 0.2 \text{ V}$ , $V_{IN} \geq V_{CC} - 0.2 \text{ V}$ or $V_{IN} \leq 0.2 \text{ V}$ , $f = 0$ | —                    | 6                  | 8                    | mA   |

### Notes

3.  $V_{IL(\text{min})} = -2.0 \text{ V}$  and  $V_{IH(\text{max})} = V_{CC} + 2 \text{ V}$  for pulse durations of less than 20 ns.

4. Typical values are included for reference only and are not guaranteed or tested. Typical values are measured at  $V_{CC} = 1.8 \text{ V}$  (for  $V_{CC}$  range of 1.65 V – 2.2 V),  $V_{CC} = 3 \text{ V}$  (for  $V_{CC}$  range of 2.2 V – 3.6 V), and  $V_{CC} = 5 \text{ V}$  (for  $V_{CC}$  range of 4.5 V – 5.5 V),  $T_A = 25 \text{ °C}$ .

5. This parameter is guaranteed by design and not tested.

## Capacitance

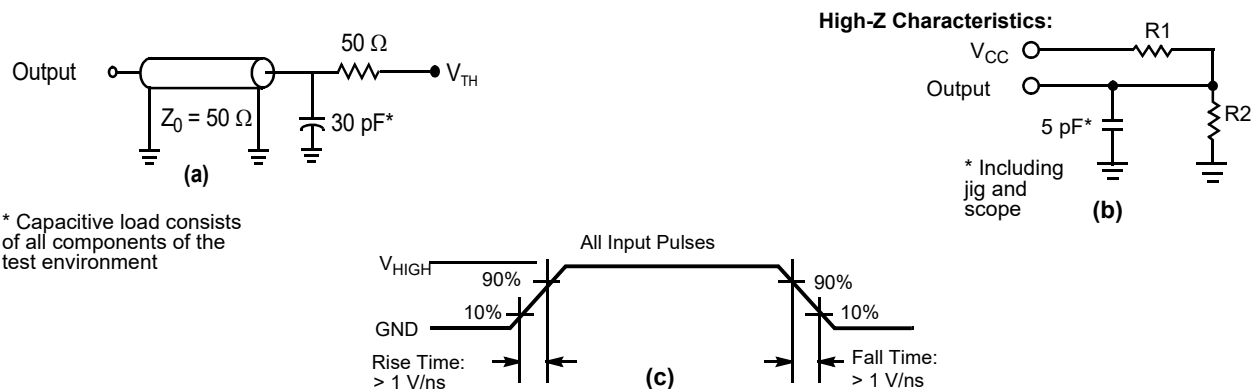
| Parameter <sup>[6]</sup> | Description       | Test Conditions                                                                            | 36-pin SOJ | 44-pin TSOP II | Unit |
|--------------------------|-------------------|--------------------------------------------------------------------------------------------|------------|----------------|------|
| $C_{IN}$                 | Input capacitance | $T_A = 25\text{ }^{\circ}\text{C}$ , $f = 1\text{ MHz}$ ,<br>$V_{CC} = V_{CC}(\text{typ})$ | 10         | 10             | pF   |
| $C_{OUT}$                | I/O capacitance   |                                                                                            | 10         | 10             | pF   |

## Thermal Resistance

| Parameter <sup>[6]</sup> | Description                              | Test Conditions                                                                | 36-pin SOJ | 44-pin TSOP II | Unit                 |
|--------------------------|------------------------------------------|--------------------------------------------------------------------------------|------------|----------------|----------------------|
| $\Theta_{JA}$            | Thermal resistance (junction to ambient) | Still air, soldered on a $3 \times 4.5$ inch, four-layer printed circuit board | 59.52      | 68.85          | $^{\circ}\text{C/W}$ |
| $\Theta_{JC}$            | Thermal resistance (junction to case)    |                                                                                | 31.48      | 15.97          | $^{\circ}\text{C/W}$ |

## AC Test Loads and Waveforms

Figure 3. AC Test Loads and Waveforms <sup>[7]</sup>



| Parameters | 1.8 V | 3.0 V | 5.0 V | Unit     |
|------------|-------|-------|-------|----------|
| R1         | 1667  | 317   | 317   | $\Omega$ |
| R2         | 1538  | 351   | 351   | $\Omega$ |
| $V_{TH}$   | 0.9   | 1.5   | 1.5   | V        |
| $V_{HIGH}$ | 1.8   | 3     | 3     | V        |

### Notes

- Tested initially and after any design or process changes that may affect these parameters.
- Full-device AC operation assumes a  $100\text{-}\mu\text{s}$  ramp time from 0 to  $V_{CC}(\text{min})$  and a  $100\text{-}\mu\text{s}$  wait time after  $V_{CC}$  stabilization.

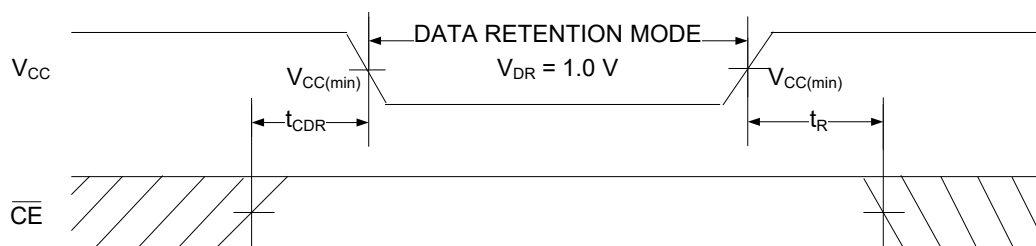
## Data Retention Characteristics

Over the operating range of  $-40\text{ }^{\circ}\text{C}$  to  $85\text{ }^{\circ}\text{C}$

| Parameter                | Description                          | Conditions                                                                                                                                                   | Min | Max | Unit |
|--------------------------|--------------------------------------|--------------------------------------------------------------------------------------------------------------------------------------------------------------|-----|-----|------|
| $V_{DR}$                 | $V_{CC}$ for data retention          |                                                                                                                                                              | 1   | –   | V    |
| $I_{CCDR}$               | Data retention current               | $V_{CC} = 1.2\text{ V}$ , $\overline{CE} \geq V_{CC} - 0.2\text{ V}$ <sup>[8]</sup> ,<br>$V_{IN} \geq V_{CC} - 0.2\text{ V}$ , or $V_{IN} \leq 0.2\text{ V}$ | –   | 8   | mA   |
| $t_{CDR}$ <sup>[9]</sup> | Chip deselect to data retention time |                                                                                                                                                              | 0   | –   | ns   |
| $t_R$ <sup>[8, 9]</sup>  | Operation recovery time              | $V_{CC} \geq 2.2\text{ V}$                                                                                                                                   | 10  | –   | ns   |
|                          |                                      | $V_{CC} < 2.2\text{ V}$                                                                                                                                      | 15  | –   | ns   |

## Data Retention Waveform

Figure 4. Data Retention Waveform <sup>[8]</sup>



### Notes

8. Full-device operation requires linear  $V_{CC}$  ramp from  $V_{DR}$  to  $V_{CC(min)}$   $\geq 100\text{ }\mu\text{s}$  or stable at  $V_{CC(min)}$   $\geq 100\text{ }\mu\text{s}$ .
9. These parameters are guaranteed by design.

## AC Switching Characteristics

Over the operating range of –40 °C to 85 °C

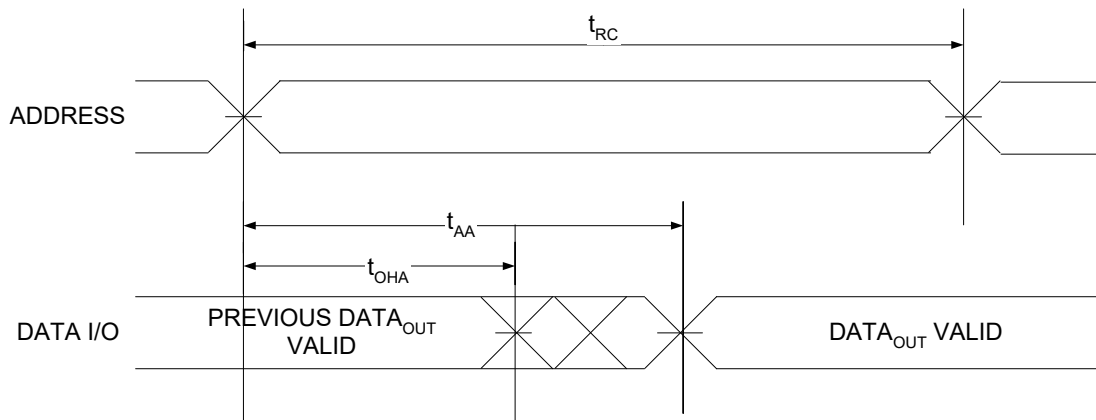
| Parameter <sup>[10]</sup>       | Description                               | 10 ns |     | 15 ns |     | Unit |
|---------------------------------|-------------------------------------------|-------|-----|-------|-----|------|
|                                 |                                           | Min   | Max | Min   | Max |      |
| Read Cycle                      |                                           |       |     |       |     |      |
| t <sub>RC</sub>                 | Read cycle time                           | 10    | –   | 15    | –   | ns   |
| t <sub>AA</sub>                 | Address to data                           | –     | 10  | –     | 15  | ns   |
| t <sub>OHA</sub>                | Data hold from address change             | 3     | –   | 3     | –   | ns   |
| t <sub>ACE</sub>                | CE LOW to data                            | –     | 10  | –     | 15  | ns   |
| t <sub>DOE</sub>                | OE LOW to data                            | –     | 4.5 | –     | 8   | ns   |
| t <sub>LZOE</sub>               | OE LOW to low impedance <sup>[11]</sup>   | 0     | –   | 0     | –   | ns   |
| t <sub>HZOE</sub>               | OE HIGH to High-Z <sup>[11]</sup>         | –     | 5   | –     | 8   | ns   |
| t <sub>LZCE</sub>               | CE LOW to low impedance <sup>[11]</sup>   | 3     | –   | 3     | –   | ns   |
| t <sub>HZCE</sub>               | CE HIGH to High-Z <sup>[11]</sup>         | –     | 5   | –     | 8   | ns   |
| t <sub>PU</sub>                 | CE LOW to power-up <sup>[12, 13]</sup>    | 0     | –   | 0     | –   | ns   |
| t <sub>PD</sub>                 | CE HIGH to power-down <sup>[12, 13]</sup> | –     | 10  | –     | 15  | ns   |
| Write Cycle <sup>[13, 14]</sup> |                                           |       |     |       |     |      |
| t <sub>WC</sub>                 | Write cycle time                          | 10    | –   | 15    | –   | ns   |
| t <sub>SCE</sub>                | CE LOW to write end                       | 7     | –   | 12    | –   | ns   |
| t <sub>AW</sub>                 | Address setup to write end                | 7     | –   | 12    | –   | ns   |
| t <sub>HA</sub>                 | Address hold from write end               | 0     | –   | 0     | –   | ns   |
| t <sub>SA</sub>                 | Address setup to write start              | 0     | –   | 0     | –   | ns   |
| t <sub>PWE</sub>                | WE pulse width                            | 7     | –   | 12    | –   | ns   |
| t <sub>SD</sub>                 | Data setup to write end                   | 5     | –   | 8     | –   | ns   |
| t <sub>HD</sub>                 | Data hold from write end                  | 0     | –   | 0     | –   | ns   |
| t <sub>LZWE</sub>               | WE HIGH to low impedance <sup>[11]</sup>  | 3     | –   | 3     | –   | ns   |
| t <sub>HZWE</sub>               | WE LOW to High-Z <sup>[11]</sup>          | –     | 5   | –     | 8   | ns   |

### Notes

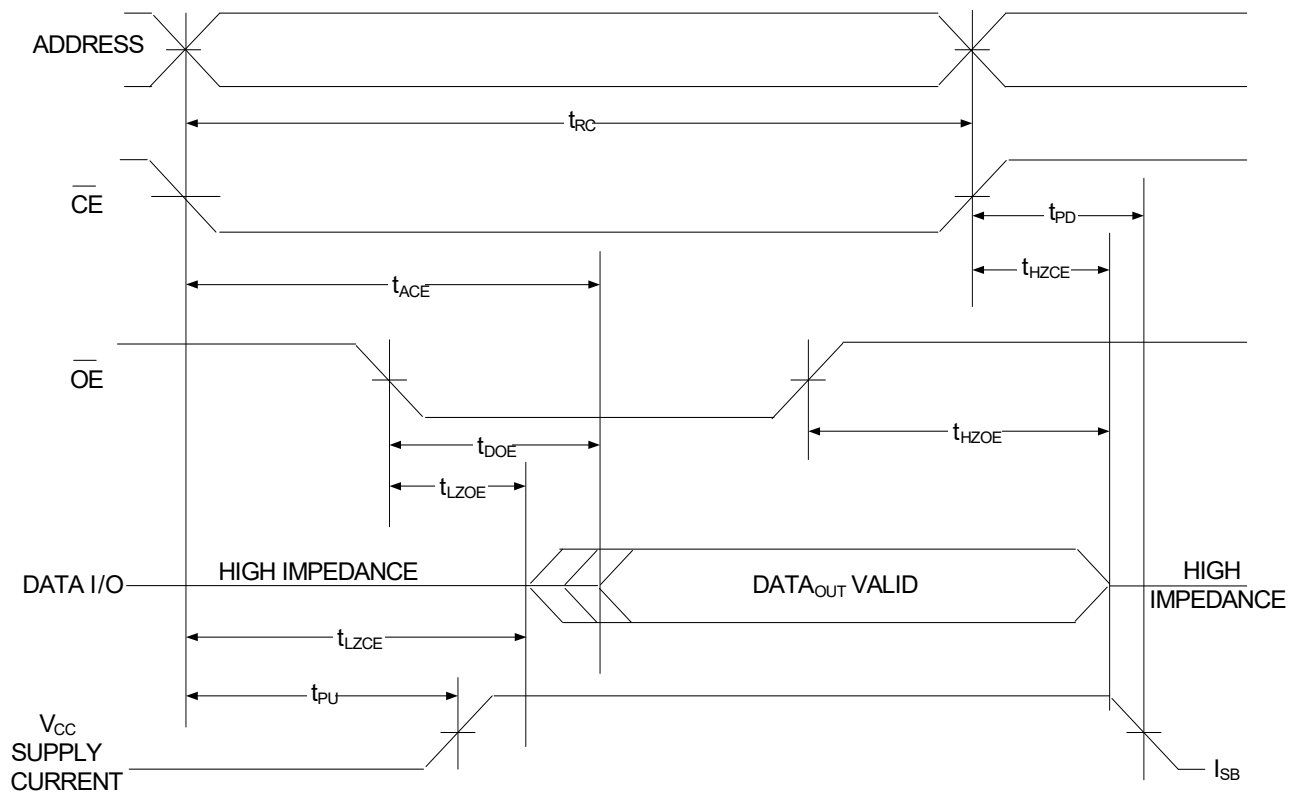
10. Test conditions assume a signal transition time (rise/fall) of 3 ns or less, timing reference levels of 1.5 V (for  $V_{CC} \geq 3$  V) and  $V_{CC}/2$  (for  $V_{CC} < 3$  V), and input pulse levels of 0 to 3 V (for  $V_{CC} \geq 3$  V) and 0 to  $V_{CC}$  (for  $V_{CC} < 3$  V). Test conditions for the read cycle use output loading, as shown in part (a) of Figure 3 on page 6, unless specified otherwise.
11.  $t_{HZOE}$ ,  $t_{HZCE}$ ,  $t_{LZWE}$ ,  $t_{LZOE}$ ,  $t_{LZCE}$ , and  $t_{LZWE}$  are specified with a load capacitance of 5 pF, as shown in part (b) of Figure 3 on page 6. Transition is measured  $\pm 200$  mV from steady state voltage.
12. These parameters are guaranteed by design and are not tested.
13. The internal write time of the memory is defined by the overlap of  $\overline{WE} = V_{IL}$ ,  $\overline{CE} = V_{IL}$ . These signals must be LOW to initiate a write, and the HIGH transition of any of these signals can terminate the operation. The input data setup and hold timing should be referenced to the edge of the signal that terminates the write.
14. The minimum write cycle pulse width in Write Cycle No. 2 ( $\overline{WE}$  Controlled,  $\overline{OE}$  LOW) should be equal to sum of  $t_{DS}$  and  $t_{HZWE}$ .

## Switching Waveforms

**Figure 5. Read Cycle No. 1 (Address Transition Controlled)** [15, 16]



**Figure 6. Read Cycle No. 2 ( $\overline{OE}$  Controlled)** [15, 16]

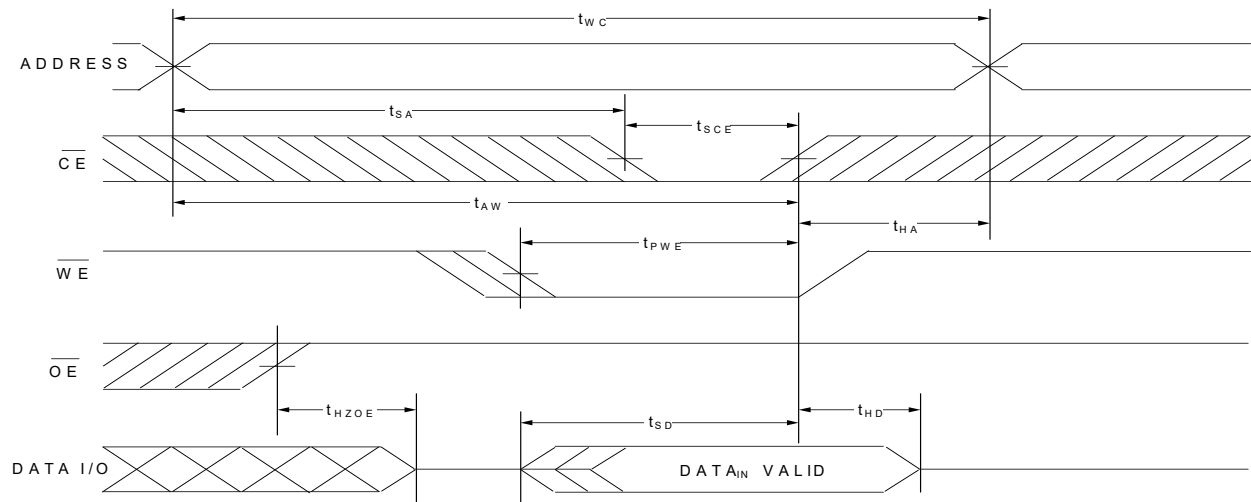


### Notes

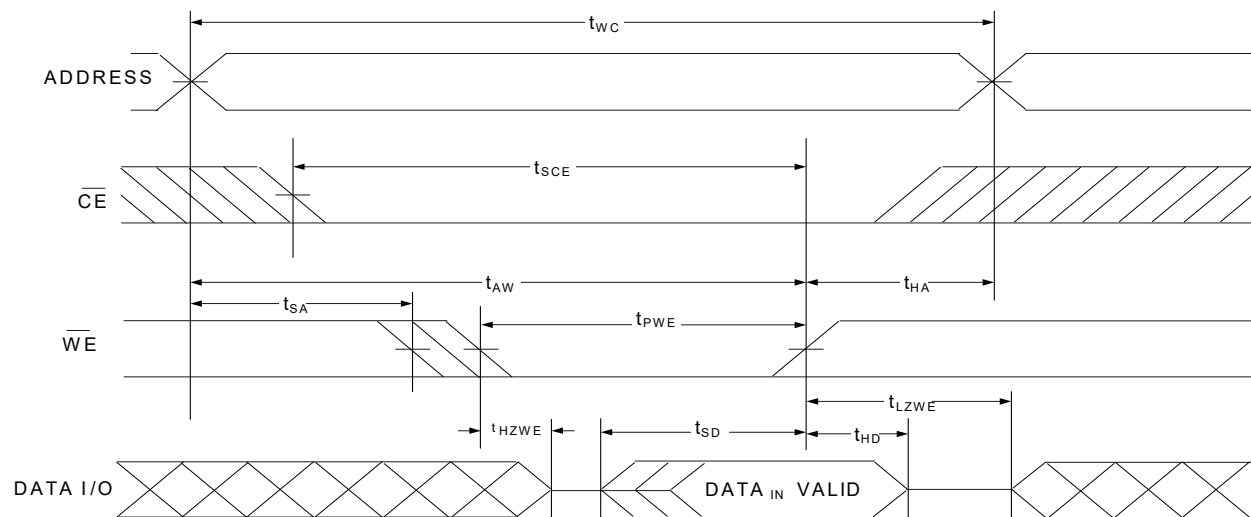
15.  $\overline{WE}$  is HIGH for the read cycle.
16. Address valid prior to or coincident with  $\overline{CE}$  LOW transition.

## Switching Waveforms (continued)

**Figure 7. Write Cycle No. 1 ( $\overline{\text{CE}}$  Controlled)** [17, 18]



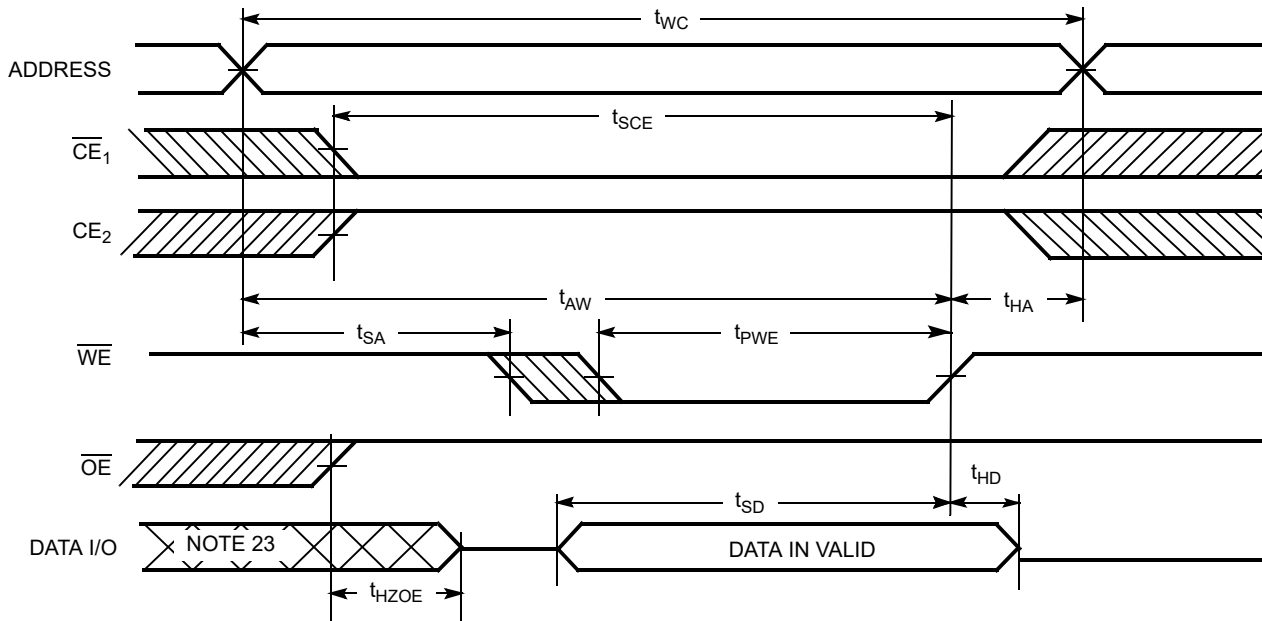
**Figure 8. Write Cycle No. 2 ( $\overline{\text{WE}}$  Controlled,  $\overline{\text{OE}}$  LOW)** [17, 18, 19]



### Notes

17. The internal write time of the memory is defined by the overlap of  $\overline{\text{WE}} = V_{IL}$ ,  $\overline{\text{CE}} = V_{IL}$ . These signals must be LOW to initiate a write, and the HIGH transition of any of these signals can terminate the operation. The input data setup and hold timing should be referenced to the edge of the signal that terminates the write.
18. Data I/O is in HI-Z state if  $\overline{\text{CE}} = V_{IH}$ , or  $\overline{\text{OE}} = V_{IH}$ .
19. The minimum write cycle pulse width should be equal to sum of  $t_{SD}$  and  $t_{HZWE}$ .

**Switching Waveforms** (continued)

**Figure 9. Write Cycle No. 3 ( $\overline{WE}$  Controlled)** [20, 21, 22]

**Notes**

20. The internal write time of the memory is defined by the overlap of  $\overline{WE} = V_{IL}$ ,  $\overline{CE} = V_{IL}$ . These signals must be LOW to initiate a write, and the HIGH transition of any of these signals can terminate the operation. The input data setup and hold timing should be referenced to the edge of the signal that terminates the write.
21. Data I/O is in HI-Z state if  $\overline{CE} = V_{IH}$ , or  $\overline{OE} = V_{IH}$ .
22. Data I/O is high impedance if  $\overline{OE} = V_{IH}$ .
23. During this period the I/Os are in output state. Do not apply input signals.

## Truth Table

| $\overline{CE}$ | $\overline{OE}$   | $\overline{WE}$   | I/O <sub>0</sub> –I/O <sub>7</sub> | Mode                       | Power                      |
|-----------------|-------------------|-------------------|------------------------------------|----------------------------|----------------------------|
| H               | X <sup>[24]</sup> | X <sup>[24]</sup> | HI-Z                               | Power down                 | Standby (I <sub>SB</sub> ) |
| L               | L                 | H                 | Data out                           | Read all bits              | Active (I <sub>CC</sub> )  |
| L               | X                 | L                 | Data in                            | Write all bits             | Active (I <sub>CC</sub> )  |
| L               | H                 | H                 | HI-Z                               | Selected, outputs disabled | Active (I <sub>CC</sub> )  |

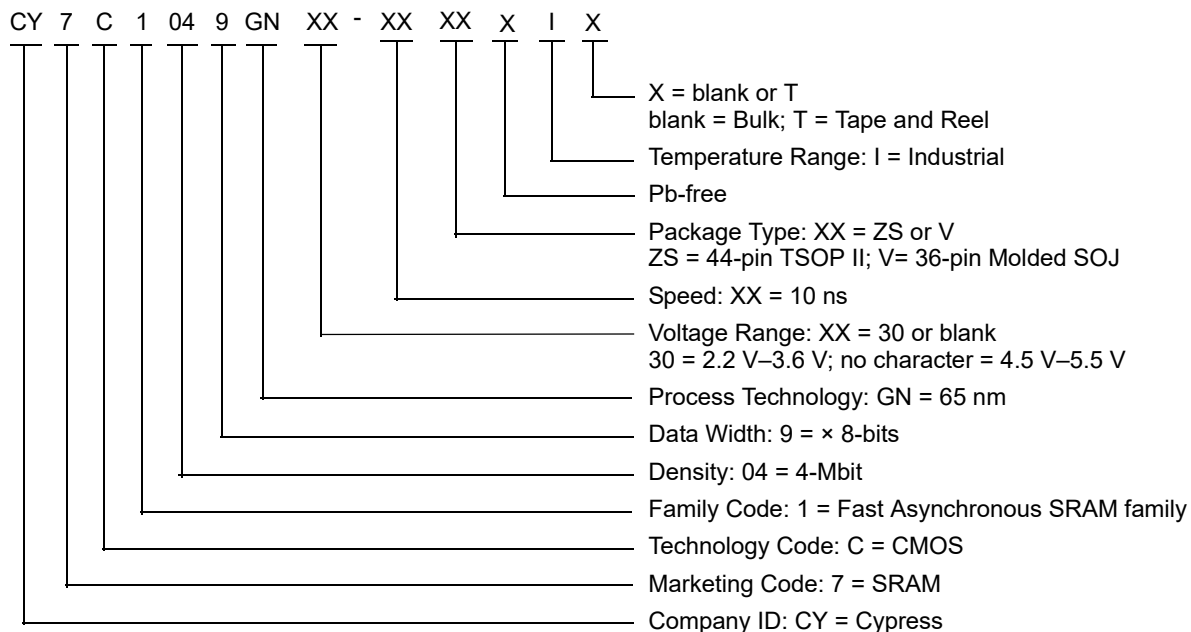
### Note

24. The input voltage levels on these pins should be either at V<sub>IH</sub> or V<sub>IL</sub>.

## Ordering Information

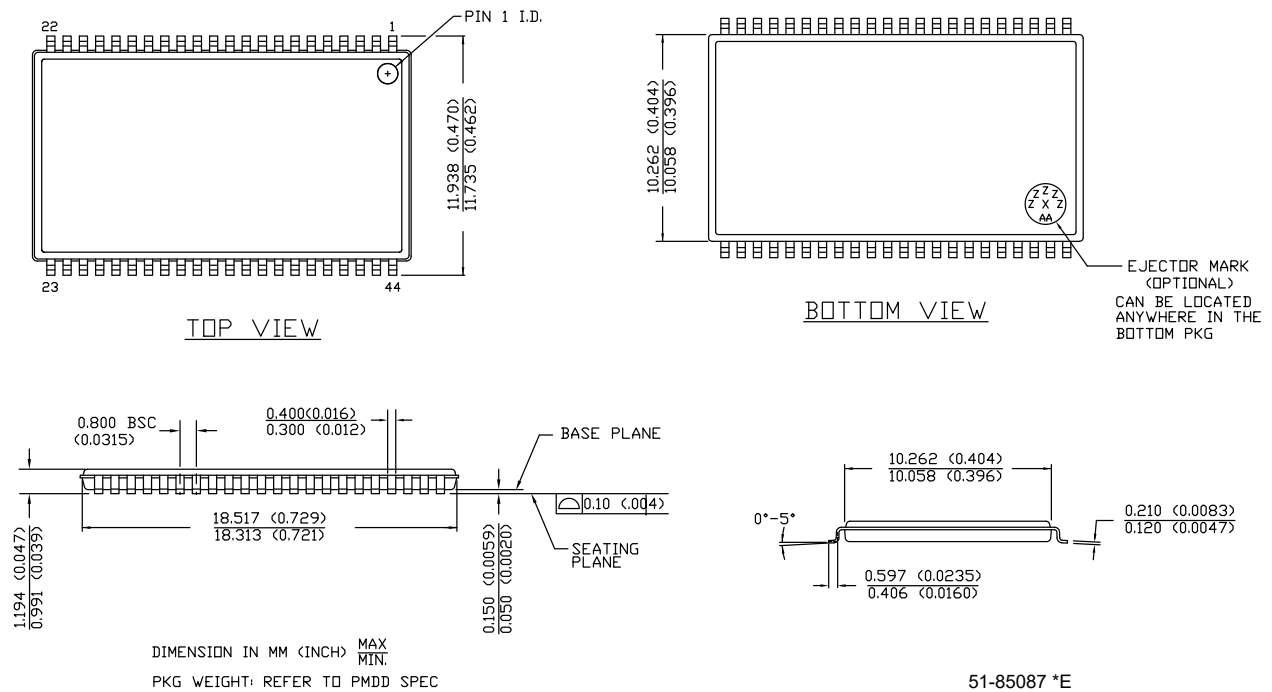
| Speed (ns) | Voltage Range | Ordering Code        | Package Diagram | Package Type (all Pb-free)       | Operating Range |
|------------|---------------|----------------------|-----------------|----------------------------------|-----------------|
| 10         | 2.2 V–3.6 V   | CY7C1049GN30-10ZSXI  | 51-85087        | 44-pin TSOP II                   | Industrial      |
|            |               | CY7C1049GN30-10ZSXIT | 51-85087        | 44-pin TSOP II, Tape and Reel    |                 |
|            |               | CY7C1049GN30-10VXI   | 51-85090        | 36-pin Molded SOJ                |                 |
|            |               | CY7C1049GN30-10VXIT  | 51-85090        | 36-pin Molded SOJ, Tape and Reel |                 |
|            | 4.5 V–5.5 V   | CY7C1049GN-10VXI     | 51-85090        | 36-pin Molded SOJ                |                 |
|            |               | CY7C1049GN-10VXIT    | 51-85090        | 36-pin Molded SOJ, Tape and Reel |                 |

## Ordering Code Definitions

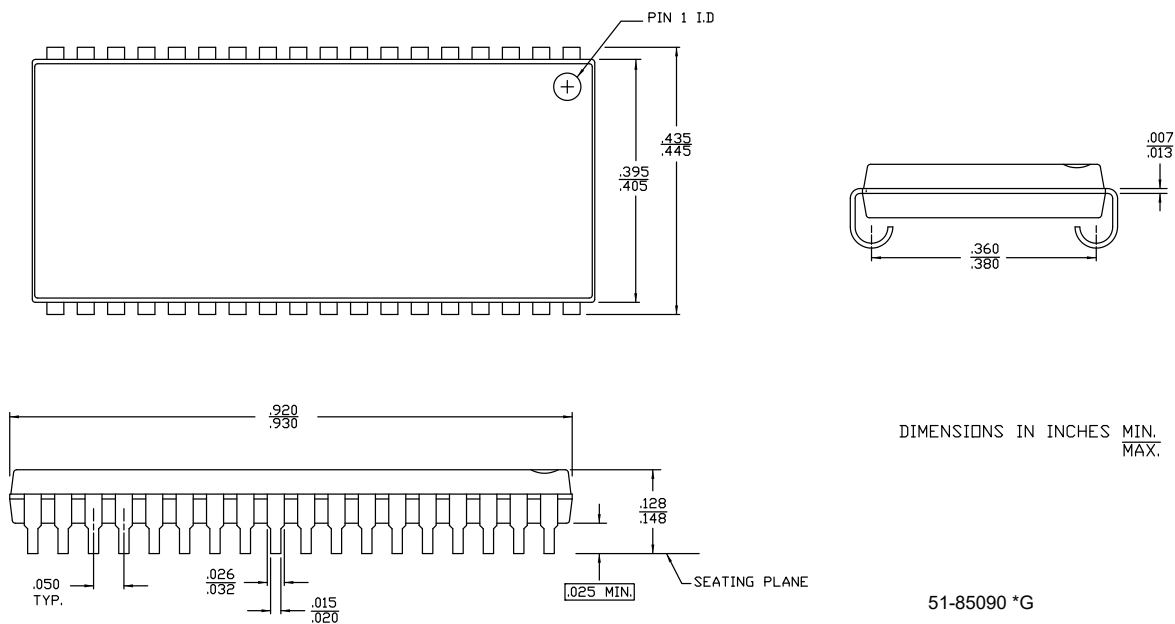


## Package Diagrams

**Figure 10. 44-pin TSOP Z44-II Package Outline, 51-85087**



**Figure 11. 36-pin SOJ V36.4 (Molded) Package Outline, 51-85090**



## Acronyms

| Acronym                 | Description                             |
|-------------------------|-----------------------------------------|
| $\overline{\text{BHE}}$ | byte high enable                        |
| $\overline{\text{BLE}}$ | byte low enable                         |
| $\overline{\text{CE}}$  | chip enable                             |
| CMOS                    | complementary metal oxide semiconductor |
| I/O                     | input/output                            |
| $\overline{\text{OE}}$  | output enable                           |
| SRAM                    | static random access memory             |
| TSOP                    | thin small outline package              |
| TTL                     | transistor-transistor logic             |
| VFBGA                   | very fine-pitch ball grid array         |
| $\overline{\text{WE}}$  | write enable                            |

## Document Conventions

### Units of Measure

| Symbol | Unit of Measure |
|--------|-----------------|
| °C     | Degrees Celsius |
| MHz    | megahertz       |
| μA     | microamperes    |
| μs     | microseconds    |
| mA     | milliamperes    |
| mm     | millimeter      |
| ns     | nanoseconds     |
| Ω      | ohms            |
| %      | percent         |
| pF     | picofarads      |
| V      | volts           |
| W      | watts           |

## Document History Page

**Document Title:** CY7C1049GN, 4-Mbit (512K words × 8-bit) Static RAM  
**Document Number:** 002-10613

| Rev. | ECN No. | Orig. of Change | Submission Date | Description of Change                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                              |
|------|---------|-----------------|-----------------|------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|
| **   | 5074703 | NILE            | 01/06/2016      | New data sheet.                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                    |
| *A   | 5082587 | NILE            | 01/12/2016      | Updated <a href="#">Logic Block Diagram – CY7C1049GN</a> .<br>Updated <a href="#">Ordering Information</a> :<br>Updated part numbers.                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                              |
| *B   | 5437570 | NILE            | 09/15/2016      | Updated <a href="#">DC Electrical Characteristics</a> :<br>Removed details of $V_{OH}$ parameter corresponding to “2.7 V to 3.6 V” and Test Condition “ $V_{CC} = \text{Min}$ , $I_{OH} = -4.0 \text{ mA}$ ”.<br>Added details of $V_{OH}$ parameter corresponding to “2.7 V to 3.0 V” and Test Condition “ $V_{CC} = \text{Min}$ , $I_{OH} = -4.0 \text{ mA}$ ”.<br>Added details of $V_{OH}$ parameter corresponding to “3.0 V to 3.6 V” and Test Condition “ $V_{CC} = \text{Min}$ , $I_{OH} = -4.0 \text{ mA}$ ”.<br>Changed minimum value of $V_{IH}$ parameter corresponding to “4.5 V to 5.5 V” from 2.2 V to 2 V.<br>Updated Note 3 (Replaced “2 ns” with “20 ns”).<br>Updated <a href="#">Ordering Information</a> :<br>Updated part numbers.<br>Updated to new template. |
| *C   | 5966829 | NILE            | 11/14/2017      | Updated <a href="#">Switching Waveforms</a> :<br>Updated <a href="#">Figure 6</a> .<br>Updated <a href="#">Figure 7</a> .<br>Updated <a href="#">Figure 8</a> .<br>Updated <a href="#">Figure 9</a> .<br>Updated to new template.<br>Completing Sunset Review.                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                     |

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